

# NL17SZ126

## Non-Inverting 3-State Buffer

The NL17SZ126 is a high performance single noninverting buffer operating from a 1.65 V to 5.5 V supply.

### Features

- Extremely High Speed:  $t_{PD}$  2.6 ns (typical) at  $V_{CC} = 5.0$  V
- Designed for 1.65 V to 5.5 V  $V_{CC}$  Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTTL Compatible – Interface Capability With 5.0 V TTL Logic with  $V_{CC} = 3.0$  V
- LVC MOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- 3–State OE Input is Active HIGH
- Replacement for NC7SZ126
- Chip Complexity = 36 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

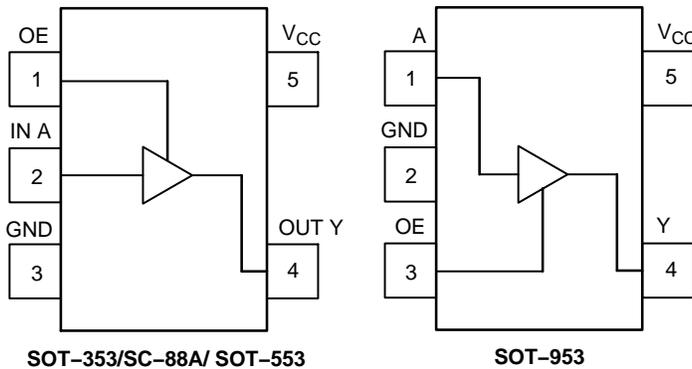


Figure 1. Pinout (Top View)

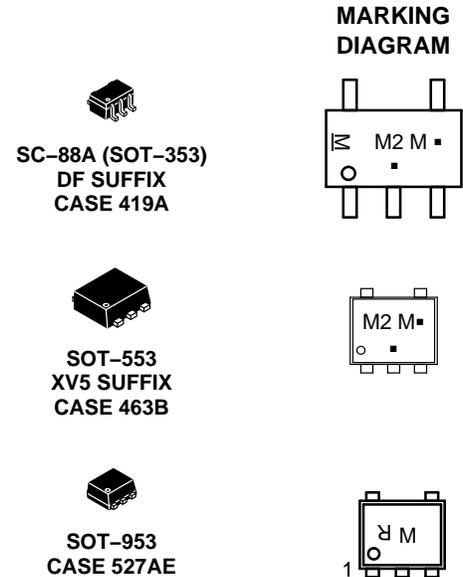


Figure 2. Logic Symbol



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M2 or R = Specific Device Code  
(R with 180 degree clockwise rotation)  
M = Date Code  
▪ = Pb–Free Package

(Note: Microdot may be in either location)  
\*Date Code orientation and/or position may vary depending upon manufacturing location.

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

# NL17SZ126

## PIN ASSIGNMENT (SOT-353/SC-88A/SOT-553/UDFN)

Pin	Function
1	OE
2	IN A
3	GND
4	OUT Y
5	V <sub>CC</sub>

## PIN ASSIGNMENT (SOT-953)

Pin	Function
1	IN A
2	GND
3	OE
4	OUT Y
5	V <sub>CC</sub>

## FUNCTION TABLE

Input		Output
OE	A	Y
H	L	L
H	H	H
L	X	Z

X = Don't Care

## MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage	-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage (SOT-353/SC-88A/SOT-553 Packages)	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (SOT-953 Package) Output at High or Low State Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> +0.5 -0.5 to +0.5	V
I <sub>IK</sub>	DC Input Diode Current	-50	mA
I <sub>OK</sub>	DC Output Diode Current (SOT-353/SC-88A/SOT-553 Packages) V <sub>OUT</sub> < GND, V <sub>OUT</sub> > V <sub>CC</sub>	±50	mA
I <sub>OK</sub>	DC Output Diode Current (SOT-953 Package) V <sub>OUT</sub> < GND	-50	mA
I <sub>OUT</sub>	DC Output Sink Current	±50	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T <sub>J</sub>	Junction Temperature Under Bias	+150	°C
θ <sub>JA</sub>	Thermal Resistance (Note 1) SC-70/SC-88A	350	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C SC-70/SC-88A	150	mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below GND at 125°C (Note 5)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

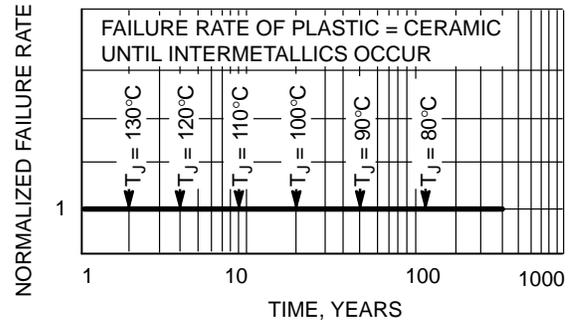
1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace with no air flow.
2. Tested to EIA/JESD22-A114-A.
3. Tested to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage	1.65	5.5	V
V <sub>IN</sub>	DC Input Voltage	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (SOT-353/SC-88A/SOT-553 Packages)	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (SOT-953 Package)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range	-40	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	V <sub>CC</sub> = 1.8 V ± 0.15 V V <sub>CC</sub> = 2.5 V ± 0.2 V V <sub>CC</sub> = 3.0 V ± 0.3 V V <sub>CC</sub> = 5.0 V ± 0.5 V		ns/V

**DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES**

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0



**Figure 3. Failure Rate versus Time Junction Temperature**

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## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-40°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
V <sub>OH</sub>	High-Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> = -100 μA	1.65	1.55	1.65		1.55		V
			1.8	1.7	1.8		1.7		
			2.3	2.2	2.3		2.2		
			3.0	2.9	3.0		2.9		
			4.5	4.4	4.5		4.4		
		I <sub>OH</sub> = -4 mA I <sub>OH</sub> = -8 mA I <sub>OH</sub> = -16 mA I <sub>OH</sub> = -24 mA I <sub>OH</sub> = -32 mA	1.65	1.29	1.52		1.29		V
			2.3	1.9	2.15		1.9		
			3.0	2.4	2.80		2.4		
			3.0	2.3	2.68		2.3		
			4.5	3.8	4.20		3.8		
V <sub>OL</sub>	Low-Level Output Voltage V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.65		0.0	0.1		0.1	V
			1.8		0.0	0.1		0.1	
			2.3		0.0	0.1		0.1	
			3.0		0.0	0.1		0.1	
			4.5		0.0	0.1		0.1	
		I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 8 mA I <sub>OL</sub> = 16 mA I <sub>OL</sub> = 24 mA I <sub>OL</sub> = 32 mA	1.65		0.08	0.24		0.24	V
			2.3		0.10	0.30		0.30	
			3.0		0.15	0.40		0.40	
			3.0		0.22	0.55		0.55	
			4.5		0.22	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μA
I <sub>OZ</sub>	3-State Output Leakage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> 0 V ≤ V <sub>OUT</sub> ≤ 5.5 V	1.65 to 5.5			±0.5		±5.0	μA
I <sub>OFF</sub>	Power Off Leakage Current (SOT-353/ SC-88A/SOT-553 Packages)	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0			1.0		10	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = 5.5 V or GND	5.5			1.0		10	μA

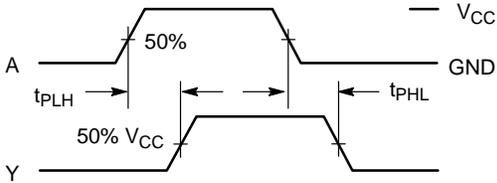
## AC ELECTRICAL CHARACTERISTICS (t<sub>R</sub> = t<sub>F</sub> = 3.0 ns)

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-40°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay AN to YN (Figures 4, and 5, Table 1)	R <sub>L</sub> = 1 MΩ C <sub>L</sub> = 15 pF	1.8 ± 0.15	2.0	9.5	12	2.0	12.5	ns
		R <sub>L</sub> = 1 MΩ C <sub>L</sub> = 15 pF	2.5 ± 0.2	1.0	3.4	7.5	1.0	8.0	
		R <sub>L</sub> = 1 MΩ C <sub>L</sub> = 15 pF R <sub>L</sub> = 500 Ω C <sub>L</sub> = 50 pF	3.3 ± 0.3	0.8 1.2		5.2 5.7	0.8 1.2	5.5 6.0	
		R <sub>L</sub> = 1 MΩ C <sub>L</sub> = 15 pF R <sub>L</sub> = 500 Ω C <sub>L</sub> = 50 pF	5.0 ± 0.5	0.5 0.8		4.5 5.0	0.5 0.8	4.8 5.3	
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time (Figures 6, 7 and 8, Table 1)	R <sub>L</sub> = 250 Ω C <sub>L</sub> = 50 pF	1.8 ± 0.15	2.0	9.0	10.5	2.0	12.5	ns
			2.5 ± 0.2	1.8		8.5	1.8	9.0	
			3.3 ± 0.3	1.2		6.2	1.2	6.5	
			5.0 ± 0.5	0.8		5.5	0.8	5.8	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time (Figures 6, 7 and 8, Table 1)	R <sub>L</sub> and R1 = 500 Ω C <sub>L</sub> = 50 pF	2.5 ± 0.2	1.5		8.0	1.5	8.5	ns
			2.5 ± 0.2	1.5		8.0	1.5	8.5	
			3.3 ± 0.3	0.8		5.7	0.8	6.0	
			5.0 ± 0.5	0.3		4.7	0.3	5.0	

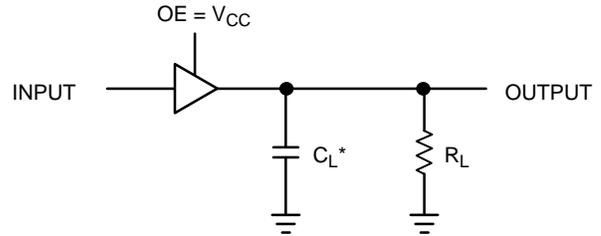
**CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	2.5	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	2.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, V <sub>CC</sub> = 3.3 V, V <sub>I</sub> = 0 V or V <sub>CC</sub> 10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	9 11	pF

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

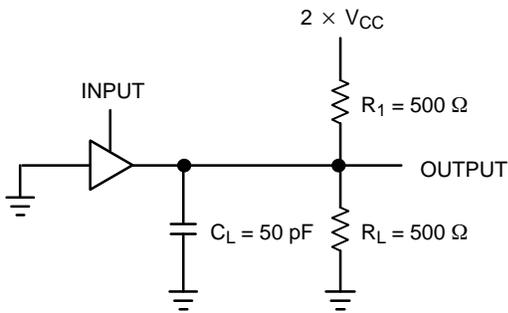


**Figure 4. Switching Waveform**



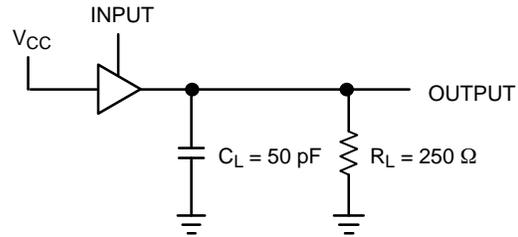
\*Includes all probe and jig capacitance.  
A 1-MHz square input wave is recommended for propagation delay tests.

**Figure 5. t<sub>PLH</sub> or t<sub>PHL</sub>**



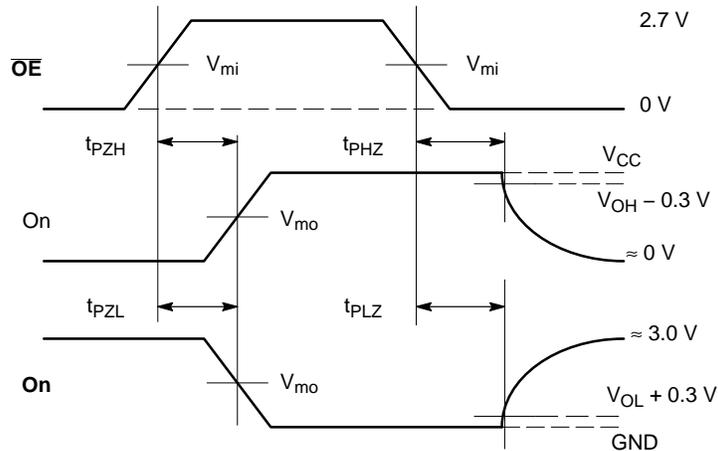
A 1-MHz square input wave is recommended for propagation delay tests.

**Figure 6. t<sub>PZL</sub> or t<sub>PLZ</sub>**



A 1-MHz square input wave is recommended for propagation delay tests.

**Figure 7. t<sub>PZH</sub> or t<sub>PHZ</sub>**



**Figure 8. AC Output Enable and Disable Waveform**

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**Table 1. Output Enable and Disable Times**

$t_R = t_F = 2.5$  ns, 10% to 90%;  $f = 1$  MHz;  $t_W = 500$  ns

Symbol	$V_{CC}$		
	$3.3\text{ V} \pm 0.3\text{ V}$	$2.7\text{ V}$	$2.5\text{ V} \pm 0.2\text{ V}$
$V_{mi}$	1.5 V	1.5 V	$V_{CC}/2$
$V_{mo}$	1.5 V	1.5 V	$V_{CC}/2$

## DEVICE ORDERING INFORMATION

Device	Package Type	Shipping <sup>†</sup>
NL17SZ126DFT2G	SC70-5/SC-88A/SOT-353 (Pb-Free)	3000 / Tape & Reel
NLV17SZ126DFT2G*	SC70-5/SC-88A/SOT-353 (Pb-Free)	3000 / Tape & Reel
NL17SZ126XV5T2G	SOT-553 (Pb-Free)	4000 / Tape & Reel
NL17SZ126P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel

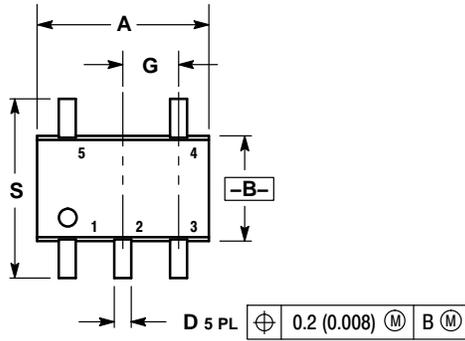
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

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## PACKAGE DIMENSIONS

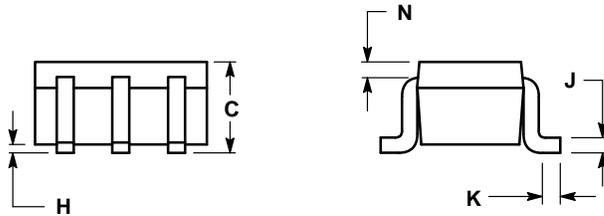
SC-88A (SC-70-5/SOT-353)  
CASE 419A-02  
ISSUE L



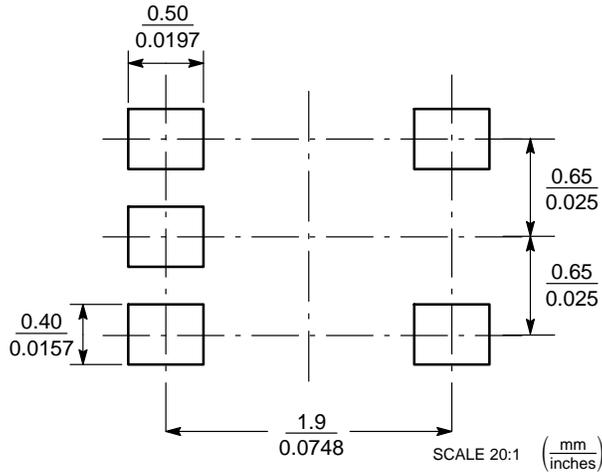
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20



### SOLDER FOOTPRINT\*

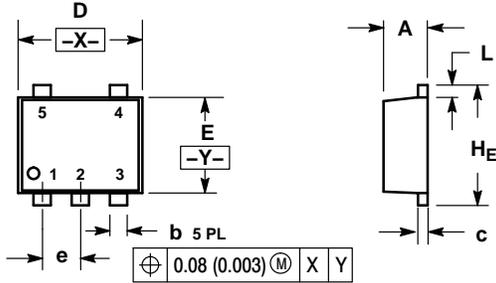


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NL17SZ126

## PACKAGE DIMENSIONS

### SOT-553, 5 LEAD CASE 463B ISSUE B

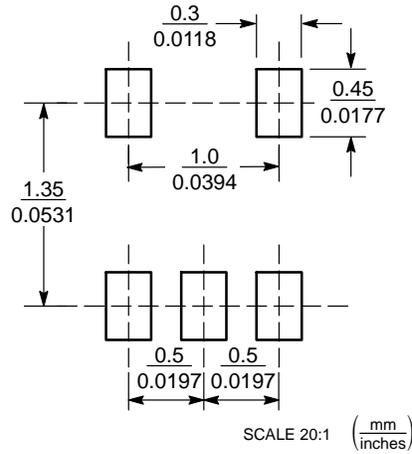


#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
c	0.08	0.13	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.063	0.067
E	1.10	1.20	1.30	0.043	0.047	0.051
e	0.50 BSC			0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.063	0.067

### SOLDERING FOOTPRINT\*

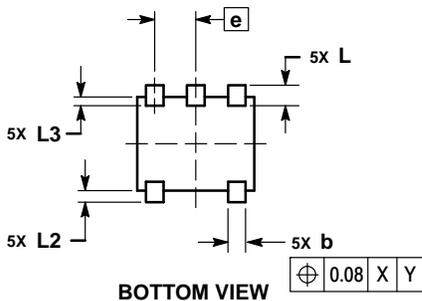
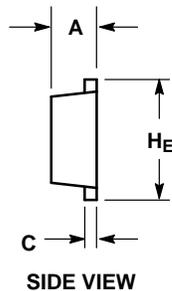
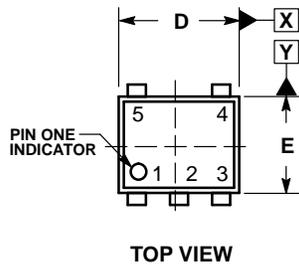


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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## PACKAGE DIMENSIONS

**SOT-953**  
CASE 527AE  
ISSUE E

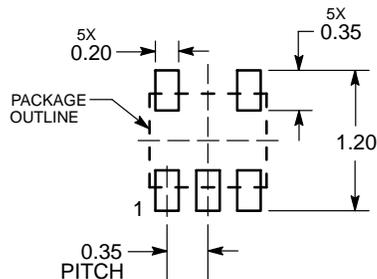


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.34	0.37	0.40
b	0.10	0.15	0.20
C	0.07	0.12	0.17
D	0.95	1.00	1.05
E	0.75	0.80	0.85
e	0.35 BSC		
He	0.95	1.00	1.05
L	0.175 REF		
L2	0.05	0.10	0.15
L3	---	---	0.15

**SOLDERING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

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